

Appearance of Universal Metallic Dispersion in a Doped Mott Insulator

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We have investigated the dispersion renormalization Z_{disp} in $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ (LSCO) over the wide doping range of $x = 0.03 - 0.30$, for binding energies extending to several hundred meV's. Strong correlation effects conspire in such a way that the system exhibits an LDA-like dispersion which essentially 'undresses' ($Z_{disp} \rightarrow 1$) as the Mott insulator is approached. Our finding that the Mott insulator contains 'nascent' or 'preformed' metallic states with a vanishing spectral weight offers a challenge to existing theoretical scenarios for cuprates.

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Under strong electronic correlations the parent compounds of all cuprate high-temperature superconductors assume the so-called Mott-Hubbard insulating state, rather than the conventional metallic state. By what routes these insulators accomplish the miraculous transformation into superconductors with the addition of electrons or holes is a question of intense current interest, which bears on ongoing debates surrounding the interplay between electron correlations, magnetism, lattice effects, and the mechanism of high-temperature superconductivity.¹ In this study we consider the classic superconductor $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ (LSCO) over the wide doping range of $x = 0.03 - 0.30$, delineating how the electronic spectrum evolves with doping for binding energies extending to several hundred meV's. Our analysis indicates that this Mott insulator contains 'nascent' or 'preformed' metallic states, which develop finite spectral weight with doping, but otherwise undergo relatively little change in dispersion over a wide doping range. Our findings challenge existing theoretical scenarios for cuprates.

We have carried out extensive angle-resolved photoemission (ARPES) measurements from LSCO single crystals covering a wide range of dopings, momenta and binding energies. Although the incoherent part of the spectrum behaves quite anomalously, we find that many-body effects conspire in such a way that insofar as the coherent part of the spectrum is concerned, at least its underlying dispersion is reasonably described by the conventional band-theory picture, significantly broadened lineshapes and 'kinks' in the dispersion notwithstanding. Surprisingly, even with the addition of just a few percent holes in

the insulator, the full-blown metallic spectrum seemingly turns on with little renormalization of the dispersion. In particular, the spectrum displays the presence of the tell-tale van Hove singularity (VHS) whose location in energy and three-dimensionality are in accord with the band theory predictions. Furthermore, this metallic spectrum is 'universal' in the sense that it depends weakly on doping, in sharp contrast to the common expectation that dispersion is renormalized to zero at half-filling.

The band structure results are based on all electron, full-potential computations within local density approximation (LDA) using the tetragonal lattice structure², and include effects of La/Sr substitution within the framework of the virtual crystal approximation³. The ARPES measurements were carried out on Beamline 10.0.1 at the ALS using Scienta 200, 2002, and R4000 electron energy analysers for 55 eV light with strong in-plane polarization. The energy resolution is 15-20 meV, and the angular resolution is 0.3 degrees for the 14 degrees angular mode. All data were taken at $T=20\text{K}$.

We set the stage for our discussion with the help of Fig. 1, which shows typical spectra from LSCO in the form of energy distribution curves (EDCs) at two different dopings for a series of momenta. Considering the overdoped case (upper light green set), we see a coherent feature dispersing to higher binding energies and becoming broader as one moves away from the Fermi momentum k_F . This feature sits on top of a substantial incoherent background extending to quite high energies at all momenta. These basic characteristics are seen to persist in the lightly doped sample (lower dark blue set), although the greatly reduced spectral weight of the co-

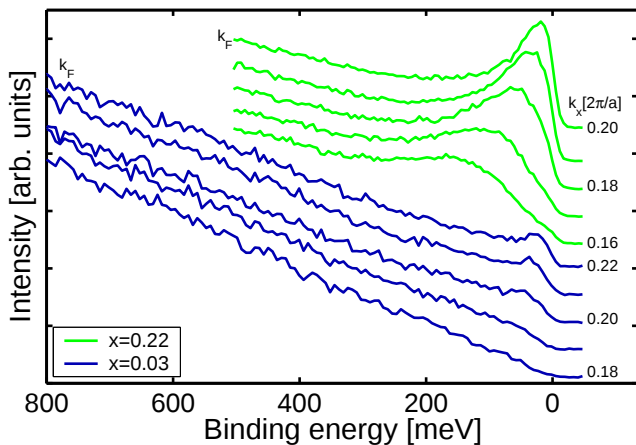


FIG. 1: (Color online) Illustrative ARPES spectra as a function of binding energy in $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ for a series of momenta along the nodal (i.e. Γ to (π, π)) direction. Results from a lightly doped insulating sample ($x = 0.03$, dark blue lines) and an overdoped metallic sample ($x = 0.22$, light green lines) are shown. Coherent spectral peak is seen to disperse to higher binding energies as one moves away from the Fermi momentum, k_F .

herent feature in relation to the incoherent part of the spectrum is very evident. Our focus in this article is on the aforementioned coherent feature in the spectrum of LSCO, and especially on delineating the evolution of its dispersion with doping.

The existence of a large, Luttinger-like, metallic ‘nascent’ or ‘underlying’ Fermi surface in LSCO has been established in previous studies, culminating in the recent systematic analysis of Sahrakorpi *et al.*⁴ and Yoshida *et al.*⁵. In contrast, here we consider spectra over a wide energy range of several hundred meV’s, show the presence of the VHS—a unique feature of the band structure—even in the lightly doped insulator, and establish unequivocally the existence of near-universal metallic dispersion in LSCO. These ‘nascent’ Fermi surfaces and dispersions are well defined despite the difficulties of identifying features in the face of loss of spectral weight as the pseudogap develops with underdoping. We emphasize that our focus is on what we may call the ‘gross’ spectrum. In other words, we are not concerned with the fine structure in the electronic spectrum associated with the well-known low energy kinks⁶, the recently discovered features at higher energy scales,^{7–11} or superconducting¹², or other¹³ leading-edge gaps.

The top row of Fig. 2 shows ARPES intensity maps from a lightly doped sample of LSCO ($x = 0.03$) for a series of binding energies. Cross-sections of the corresponding constant energy (CE) surfaces in the (k_x, k_y) plane computed from the band structure of LSCO, superposed at $k_z = 0$ (magenta lines) and $k_z = 2\pi/c$ (black lines) indicate the expected broadening of the ARPES spectra associated with interlayer coupling. At zero binding energy, i.e. the Fermi energy E_F , such CE contours give

the projection of the 3D FS of LSCO on to the (k_x, k_y) plane. Notably, the momentum region enclosed by these CE contours defines the region of allowed ARPES transitions, modulated by the effect of the ARPES matrix element.^{4,14,15} At low binding energies, the CE surface is seen from panels (a-c) to be hole-like around the $X(\pi, \pi)$ point for all k_z values. In contrast, at high energy in panel (e), after the VHS has been crossed, the CE surface becomes completely electron-like centered at Γ . The transition from a hole- to electron-like CE surface does not take place abruptly because the VHS possess a significant 3D character, extending from 85-140 meV in binding energy.

The evolution of the experimental ARPES intensity pattern with binding energy in the top row of Fig. 2 clearly follows that of the projected CE surfaces. In particular, the spectral intensity remains confined mainly within the boundaries of these projections as expected, and with increasing binding energy, the intensity first spreads towards the $M(\pi, 0)$ -points and then moves away from the M -points along a perpendicular direction, very much the way the CE surfaces transition from being hole- to electron-like. Moreover, first principles ARPES computations show that under the combined effects of the matrix element and k_z dispersion, the spectral intensity develops the characteristic ‘wing-like’ shape seen in Fig. 2, and that the spectral weight grows rapidly in the antinodal region as the VHS is approached.⁴ These results leave no doubt that metallic states, including the presence of the 3D VHS, appear in the spectrum of the insulator with the addition of only a few percent holes, even though spectral broadening and incoherent background make it hard to see this directly in the individual EDCs. The observed location in energy and three-dimensionality of the VHS is well-described by the conventional band theory picture, indicating that the energies of these metallic states undergo little renormalization in the lightly doped insulator. The evolution of the VHS over a denser binding energy mesh can be seen further in the three movies for $x = 0.03, 0.07$, and 0.12 provided as supplementary material.¹⁶ The characteristic dispersion of the VHS is quite recognizable in the emission maps of the top row of Fig. 2. and in the supplementary movies.

We demonstrate next that the aforementioned metallic dispersion is only weakly dependent on doping. Note that if this is true then the main difference in going from one doping to another would be a shift in the Fermi energy needed to accommodate the right number of holes in the filled portion of the band structure. That is, topologies of the CE surfaces and the associated emission spectra would be comparable for various dopings except for a rigid shift of the energy scales. That this is indeed the case is shown by the results for emission from the E_F for $x = 0.05 - 0.30$, presented in the bottom row of Fig. 2. For example, based on parameter free LDA computations for $x = 0.03$ and $x = 0.30$, the E_F for $x = 0.30$ is lower by 190 meV than for $x = 0.03$, so that the ARPES map for emission at a binding energy of 190 meV from $x = 0.03$ in

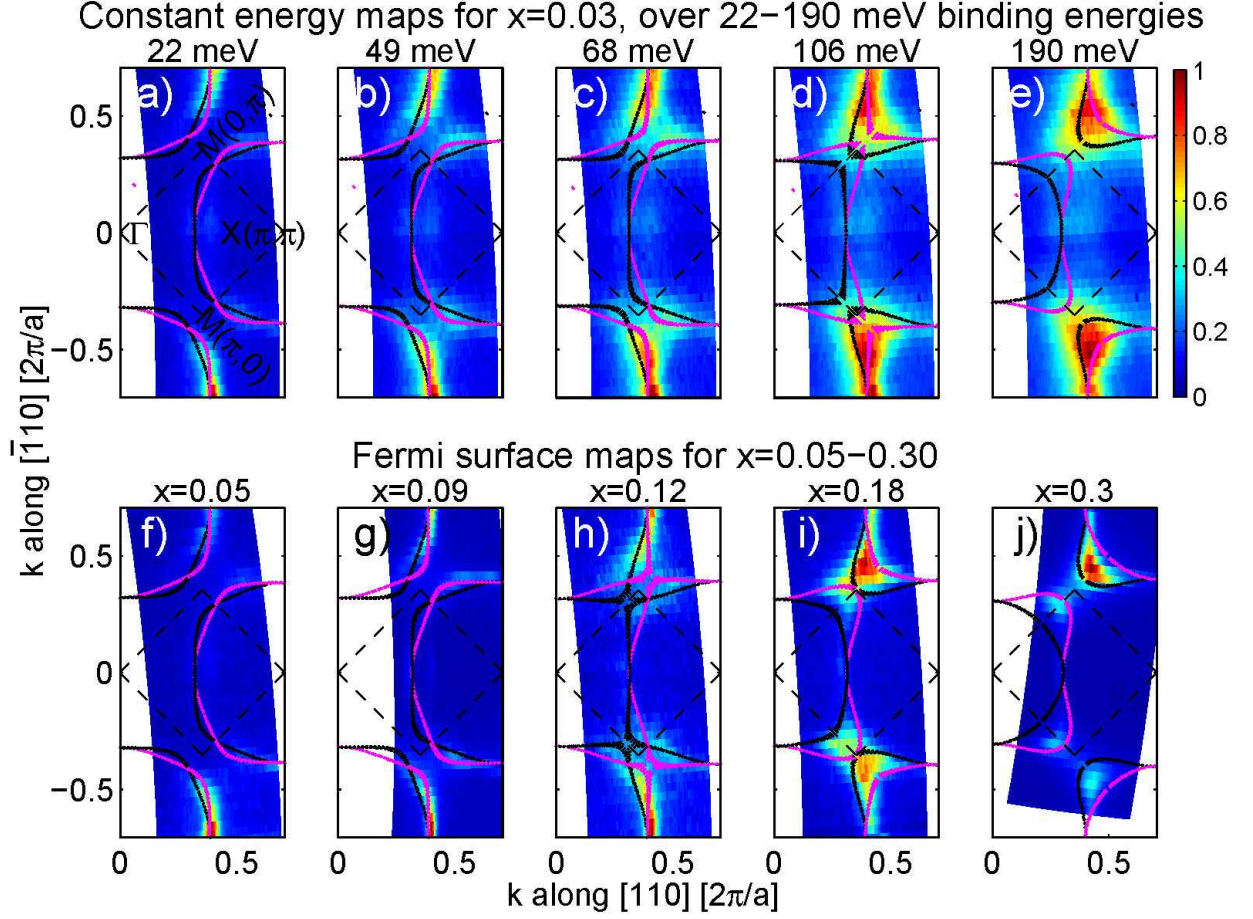


FIG. 2: (Color) Experimental ARPES intensity maps in LSCO are compared with the corresponding cuts in the (k_x, k_y) plane through the theoretical constant energy (CE) surfaces for $k_z = 0$ (magenta lines), and $k_z = 2\pi/c$ (black lines). *Top Row:* $x = 0.03$ with binding energy varying from 22 meV to 190 meV. *Bottom Row:* ARPES maps for emission from the Fermi energy for dopings varying from $x = 0.05$ to $x = 0.30$.

panel (e) can be compared with that for emission from the E_F for $x = 0.30$ in (j). In this vein, the binding energies in the various panels of the top row of Fig. 2 for $x = 0.03$ have been chosen to match the E_F shifts involved at the doping levels considered in the panels of the bottom row. Good accord is seen in all cases. We emphasize that the energy shifts corresponding to the respective panels of the top and bottom rows in Fig. 2 are based on parameter free first principles computations. These and other similar comparisons among spectra taken at different binding energies and doping levels show clearly that LSCO is characterized by a near-universal metallic dispersion despite dramatic changes in the lineshape due to interactions. This is also true for the theoretical dispersions, although slight doping dependencies can be seen for example by comparing the CE surfaces in the top and bottom frames (c) and (h) in Fig. 2.

Further insight is provided by Fig. 3, which shows plots of spectral intensity as a function of binding energy along the antinodal line (top row) and the nodal line (bottom

row) for six different dopings. The corresponding energy bands at $k_z = 0, \pi/c$ and $2\pi/c$ are overlaid in each panel. These bands are seen to differ substantially for different k_z values along the antinodal line in the upper panels but are virtually indistinguishable in the lower panels along the nodal line. The VHS, which is marked by the extremum of the band along the antinodal line, is spread over 40 meV at $x = 0.03$ doping due to the effect of k_z dispersion, and its center lies at 110 meV below E_F for $x = 0.03$, but moves to 110 meV above the E_F for $x = 0.30$ with a spread of 70 meV. Along the nodal direction, the theoretical band follows the experimental peak positions given by the black dots reasonably well, although the experimental points are shifted to the right compared to theory in most cases, indicating a slight deviation of FS shape from LDA. Along the antinodal direction, however, the spectral peaks are substantially broader due to k_z dispersion and also possible many body interactions, although most of the spectral weight lies within the k_z dispersed bands as expected in

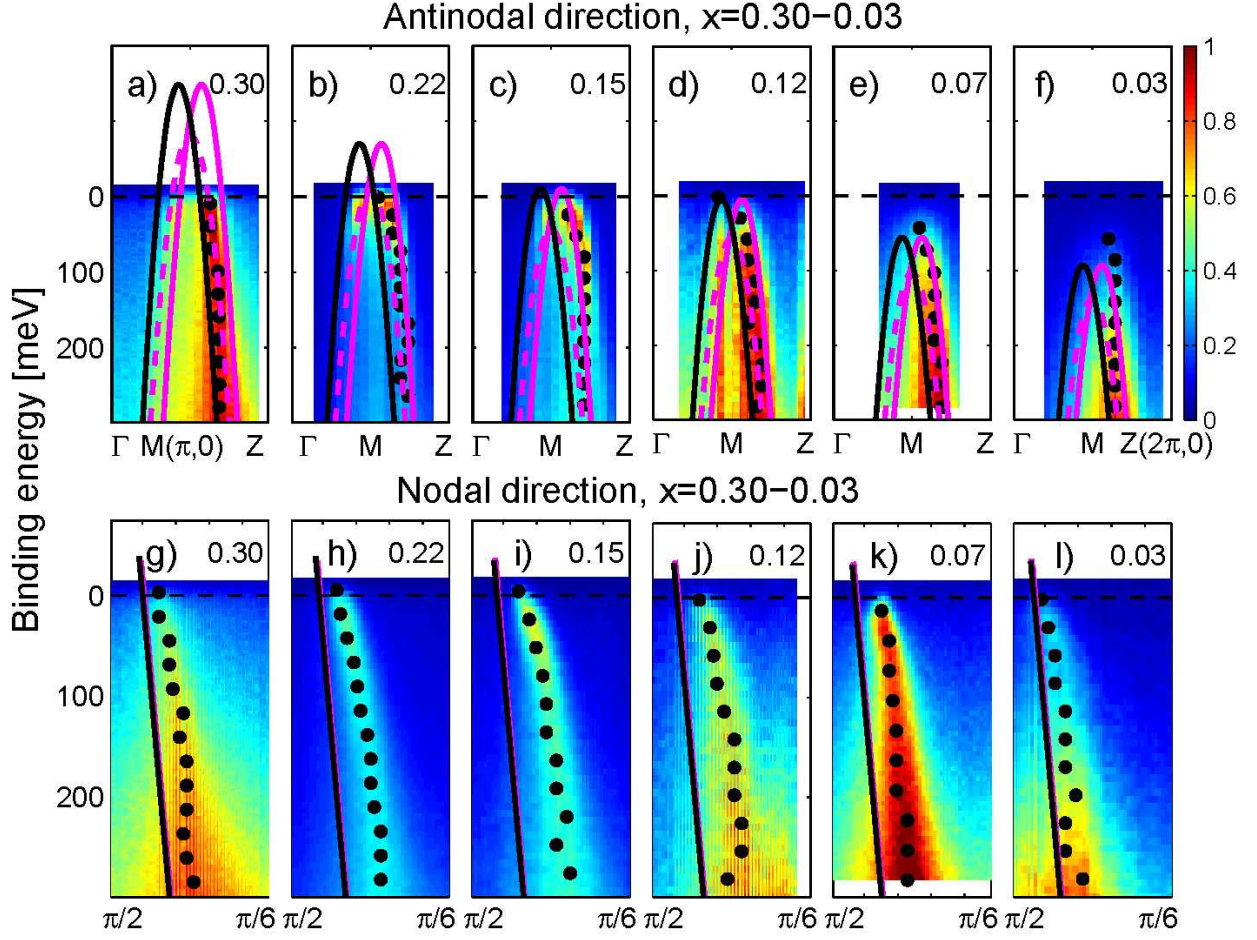


FIG. 3: (Color) ARPES intensity maps along the antinodal (top row) and nodal (bottom row) directions over the doping range $x = 0.30 - 0.03$. The corresponding computed band structures are also plotted for three different values of k_z : $k_z = 0$ (magenta solid line), $k_z = \pi/c$ (magenta dashed line), and $k_z = 2\pi/c$ (black solid line). Black dots mark positions of the peaks in the experimental spectra. Note that nodal data in the lower row are plotted on an expanded horizontal scale in order to highlight relatively small differences between gross theoretical and experimental dispersions. For each doping, the nodal and antinodal intensities are normalized to a common maximum.

Doping $x =$	0.03	0.07	0.12	0.15	0.22	0.30
Z_{disp} (nodal)	1.0 (1.2)	0.8 (1.2)	0.6 (0.8)	0.6 (0.8)	0.6 (0.7)	0.6 (0.6)
Z_{disp} (antinodal)	1.1 ± 0.2	1.3 ± 0.4	$> 0.6^*$	$> 0.6^*$	$> 0.7^*$	$> 0.7^*$

TABLE I: Estimates of dispersion renormalization factors Z_{disp} in LSCO for different dopings x in relation to the LDA values. Nodal Z_{disp} values in parenthesis are an estimate of the upper limit. Stars in the second row denote that for these dopings the values refer to the region in the vicinity of the antinodal point as discussed in the text.

a quasi-2D system.^{4,14,15}

We have examined the renormalization of dispersion in relation to the LDA values along the nodal and antinodal directions as a function of doping, and thus obtained the

associated renormalization factors Z_{disp} . These results are summarized in Table I. Our study provides new insight into the value of Z_{disp} along the antinodal direction because the VHS is a very robust feature of the LDA band structure. By determining the position of the VHS in the experimental spectrum, and comparing this position with that expected from the LDA, we can uniquely determine the overall renormalization of the spectrum along the antinodal direction with respect to the LDA. At $x = 0.03$ and $x = 0.07$, the VHS lies below the Fermi energy for all k_z values, and in these two cases, by analyzing the supplementary movies¹⁶ using different renormalization factors to scale the LDA bands, we have obtained Z_{disp} (antinodal) values of ~ 1 within the uncertainty shown in Table I, so that the LDA bands are essentially unrenormalized. For $x = 0.12$ and higher dopings, part or all of the VHS lies above the Fermi energy, so that we were only able to estimate a lower limit for Z_{disp} in the

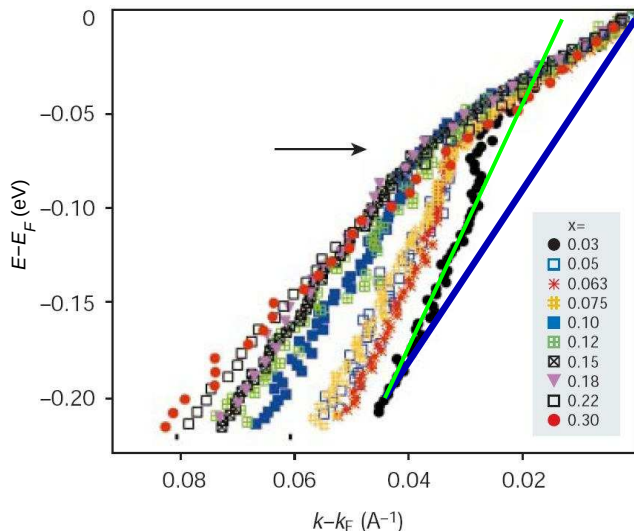


FIG. 4: (Color online) Reproduction of Fig. 1 in Zhou *et al.*¹⁷ Dark blue line drawn on the $x = 0.03$ dataset illustrates how the nodal Z_{disp} value is defined here, while the light green line gives the high energy slope used to estimate the corresponding upper limit on Z_{disp} (nodal) as discussed in the text.

vicinity of the antinodal point. There are of course no filled states at the antinodal point once the VHS moves above the Fermi energy.

Turning to the nodal direction, we note that here the effects of k_z dispersion are small, and our analysis is consistent with results available in the literature. For completeness, however, we have estimated the gross Z_{disp} (nodal) values from the nodal spectra given in Fig. 1 of Zhou *et al.*¹⁷, reproduced here as Fig. 4. In order to gain a handle on the ‘gross’ or underlying dispersion exclusive of the low energy kink (see arrow at 70 meV in Fig. 4), values of Z_{disp} (nodal) given in Table I are obtained from the slopes of the straight lines joining the point at the Fermi energy with that at 200 meV binding energy, i.e. by lines such as the dark blue line drawn for the $x = 0.03$ case in Fig. 4, and comparing this slope to the corresponding LDA values. Since the LDA values of the nodal radii do not exactly match the measured values, we have estimated Z_{disp} (nodal) by comparing LDA and experimental slopes. We also show in parentheses the values of Z_{disp} (nodal) obtained from the slopes of the high energy part of the spectrum, as given for example by the light green line for $x = 0.03$ in Fig. 4, which provides an estimate for the upper limit of Z_{disp} (nodal).

Interestingly, at the lowest doping of $x = 0.03$, the nodal as well as the antinodal renormalization factor is seen to be ~ 1 . In the optimally and overdoped regimes, the nodal renormalization factor is ~ 0.6 , while the value of the antinodal factor is estimated to be greater than 0.6. In the underdoped $x = 0.03$ case, the renormalization of states in the antinodal and nodal directions is roughly similar, but this is less clear at higher dopings. These

results are surprising since we might have expected the LDA to provide a reasonable description in the overdoped regime, and to be renormalized greatly in the underdoped case.

Even though we have shown that the gross dispersion up to several hundred meV’s is described quite well by the band theory picture, we emphasize that this does not mean that the spectrum of LSCO is conventional in nature. As shown in Fig. 1, the coherent spectral weight of these dispersive features fades away for underdoping where the pseudogap and polaronic effects kick in. The spectral weight is transferred to an incoherent feature^{18–20}, reflecting the importance of many-body physics. Our analysis thus suggests that the spectrum of the insulator already contains ‘preformed’ or ‘nascent’ metallic states, which possess zero spectral weight in the half-filled case. With doping, these states develop finite spectral weight, but otherwise undergo relatively little change in their basic character.

It is interesting to study the relationship between the renormalization of the dispersion and spectral weight within the simple Green function formalism. The Green function can be approximately written as $G = Z_\omega / [\omega - Z_\omega \epsilon_k / Z_k]$, with $Z_\omega = 1 / (1 - \partial \Sigma / \partial \omega)$, and $Z_k = 1 / (1 + \partial \Sigma / \partial \epsilon_k)$, where Σ is the self-energy. While the spectral weight renormalization is associated with Z_ω , the band dispersion renormalization is given by $Z_{disp} = Z_\omega / Z_k$. It is striking that the spectral weight in LSCO is renormalized greatly but the dispersion is not. This is not consistent with a momentum independent self-energy, since the renormalization of spectral weight would then be accompanied by a similar renormalization of dispersion, suggesting that the self-energy possesses momentum as well as energy dependencies such that the effects of the associated renormalization factors, Z_ω and Z_k ,²¹ conspire to approximately cancel each other in renormalizing dispersion. This picture however implies that the heat capacity would be renormalized only weakly with doping, which is not the case experimentally.²²

Insofar as theoretical models of strongly correlated systems are concerned, a focus of attention in the literature has been the $t - J$ model, which has been used to describe the physics of the Hubbard Hamiltonian in the large U regime. One class of $t - J$ models finds gapped insulating solutions at half-filling, which evolve with doping to yield small Fermi surface pockets²³. This route appears to be followed in $Nd_{2-x}Ce_xCuO_4$ for electron doping^{24–26}. But the present results do not show clear evidence for small pockets or other strong violations of Luttinger’s theorem²⁷. On the other hand, metallic solutions with a large Luttinger-like Fermi surface have also been reported^{12,28}, where the spectral weight Z_ω is renormalized to zero at half-filling. These solutions are closer to our observations, even though the band width is found to be strongly renormalized near half-filling, $Z_{disp} \sim J/t$. A recent variant of the $t - J$ model succeeds in capturing both the metallic and insulating aspects of the spectrum simultaneously^{29,30}. However, to our knowledge,

our finding of a large Fermi surface and a large dispersion, which is weakly dependent on doping, does not fit well within the framework of the currently available scenarios based on simple Hubbard or $t - J$ models or naive application of the classical polaron theory.

In conclusion, we have shown that metallic states appear in the electronic spectrum of high temperature superconductor $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ at all doping levels, ranging from the lightly doped insulating to the overdoped metallic regime. The gross dispersion of these states is not only near-universal in that it is weakly dependent on doping, but it is also conventional in that it is reasonably described by the standard band theory picture up to binding energies of several hundred meV's. However, the metallic states suffer substantial loss of spectral weight with underdoping and in this respect behave quite unconventionally. Our findings challenge existing

theoretical models of the cuprates and indicate the complexity with which many-body physics plays out in this fascinating material.

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